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CSD18540Q5B

SLPS488-JUNE 2014

CSD18540Q5B 60V N-Channel NexFET[™] Power MOSFETs

Features 1

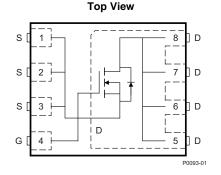
- Ultra-Low Q_a and Q_{ad}
- Low Thermal Resistance
- Avalanche Rated
- **Pb-Free Terminal Plating**
- **RoHS** Compliant
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

2 Applications

- **DC-DC** Conversion
- Secondary Side Synchronous Rectifier
- Isolated Converter Primary Side Switch
- Motor Control

3 Description

This 1.8 mΩ, 60 V, SON5x6 NexFET™ power MOSFET is designed to minimize losses in power conversion applications.



R_{DS(on)} vs V_{GS} 5 $T_{C} = 25^{\circ}C, I_{D} = 28A$ $R_{DS(on)}$ - On-State Resistance (m $\Omega)$ 4.5 $T_{C} = 125^{\circ}C, I_{D} = 28A$ 4 3.5 3 2.5 2 1.5 1 0.5 0 0 2 4 6 8 10 12 14 16 18 20 V_{GS} - Gate-to- Source Voltage (V) G001

Product Summary

T _A = 25°	C	TYPICAL VA	UNIT	
V _{DS}	Drain-to-Source Voltage	60		V
Qg	Gate Charge Total (10 V)	41		nC
Q _{gd}	Gate Charge Gate-to-Drain	6.7		nC
Б	Drain-to-Source On Resistance	$V_{GS} = 4.5 V$	2.6	mΩ
R _{DS(on)}	Drain-to-Source Off Resistance	V _{GS} = 10 V	1.8	mΩ
V _{GS(th)}	Threshold Voltage	1.9	V	

Ordering Information⁽¹⁾

Device	Qty	Media	Package	Ship
CSD18540Q5B	2500	13-Inch Reel	SON 5 × 6 mm	Tape and
CSD18540Q5BT	250	7-Inch Reel	Plastic Package	Reel

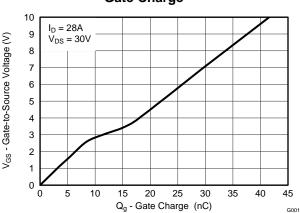
(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

$T_A = 2$	25°C	VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	60	V
V_{GS}	Gate-to-Source Voltage	±20	V
	Continuous Drain Current (Package limited)	100	
I _D	Continuous Drain Current (Silicon limited), $T_C = 25^{\circ}C$	221	А
	Continuous Drain Current ⁽¹⁾	28	
I _{DM}	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	400	А
-	Power Dissipation ⁽¹⁾	3.1	14/
PD	Power Dissipation, $T_C = 25^{\circ}C$	195	W
T _J , T _{stg}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse I_D = 80 A, L = 0.1 mH, R_G = 25 Ω	320	mJ

(1) Typical $R_{0,IA}$ = 40°C/W on a 1-inch² , 2-oz. Cu pad on a 0.06-inch thick FR4 PCB.

(2) Max $R_{\theta JC} = 0.8^{\circ}C/W$, Pulse duration $\leq 100 \ \mu$ s, duty cycle $\leq 1\%$



Gate Charge

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.



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4 Revision History

DATE	REVISION	NOTES
June 2014	*	Initial release.

5 Specifications

5.1 Electrical Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
STATIC	CHARACTERISTICS				
BV_{DSS}	Drain-to-Source Voltage	$V_{GS} = 0 V, I_D = 250 \mu A$	60		V
I _{DSS}	Drain-to-Source Leakage Current	V_{GS} = 0 V, V_{DS} = 48 V		1	μA
I _{GSS}	Gate-to-Source Leakage Current	$V_{DS} = 0 V, V_{GS} = 20 V$		100	nA
V _{GS(th)}	Gate-to-Source Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1.5 1.9	2.3	V
D	Drain-to-Source On Resistance	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 28 \text{ A}$	2.6	3.3	mΩ
R _{DS(on)}	Drain-to-Source On Resistance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 28 \text{ A}$	1.8	2.2	mΩ
g _{fs}	Transconductance	$V_{DS} = 6 V, I_D = 28 A$	116		S
DYNAMI	C CHARACTERISTICS				
C _{iss}	Input Capacitance		3250	4230	pF
C _{oss}	Output Capacitance	$V_{GS} = 0 V$, $V_{DS} = 30 V$, $f = 1 MHz$	622	808	pF
C _{rss}	Reverse Transfer Capacitance		15	20	pF
R_{G}	Series Gate Resistance		0.8	1.6	Ω
Qg	Gate Charge Total (4.5 V)		20	26	nC
Qg	Gate Charge Total (10 V)		41	53	nC
Q_{gd}	Gate Charge Gate-to-Drain	$V_{DS} = 30 \text{ V}, \text{ I}_{D} = 28 \text{ A}$	6.7		nC
Q_gs	Gate Charge Gate-to-Source		8.8		nC
Q _{g(th)}	Gate Charge at V _{th}		6.3		nC
Q _{oss}	Output Charge	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$	83		nC
t _{d(on)}	Turn On Delay Time		6		ns
t _r	Rise Time	V _{DS} = 30 V, V _{GS} = 10 V,	9		ns
t _{d(off)}	Turn Off Delay Time	$I_{DS} = 28 \text{ A}, \text{ R}_{G} = 0 \Omega$	20		ns
t _f	Fall Time		3		ns
DIODE C	CHARACTERISTICS				
V_{SD}	Diode Forward Voltage	$I_{SD} = 28 \text{ A}, V_{GS} = 0 \text{ V}$	0.8	1	V
Q _{rr}	Reverse Recovery Charge	V _{DS} = 30 V, I _F = 28 A,	145		nC
t _{rr}	Reverse Recovery Time	di/dt = 300 A/µs	82		ns

5.2 Thermal Information

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

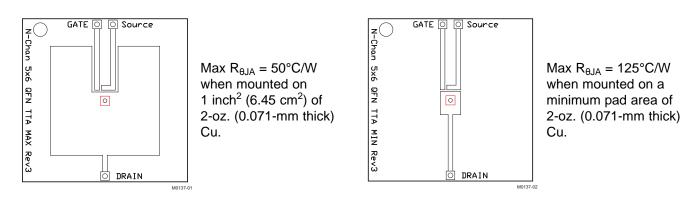
	THERMAL METRIC	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance ⁽¹⁾			0.8	°C/W
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance ⁽¹⁾⁽²⁾			50	°C/W

R_{0,JC} is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inches x 1.5-inches (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. R_{0,JC} is specified by design, whereas R_{0,JA} is determined by the user's board design.

(2) Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.

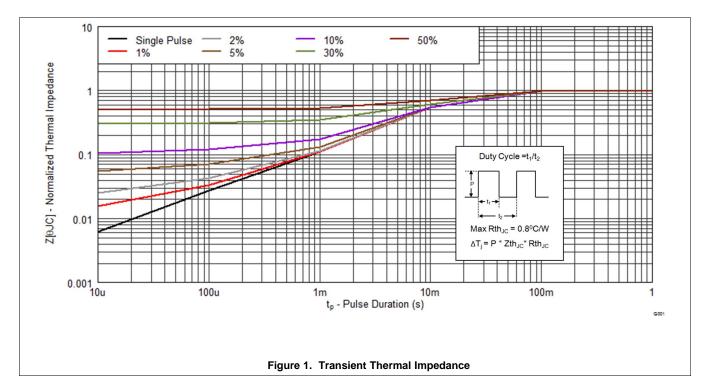
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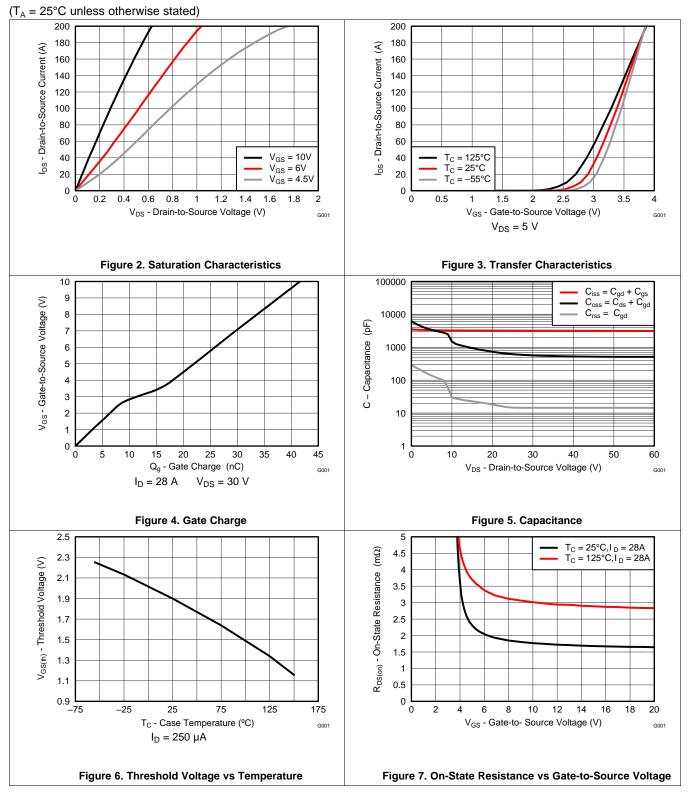
5.3 Typical MOSFET Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$





Typical MOSFET Characteristics (continued)

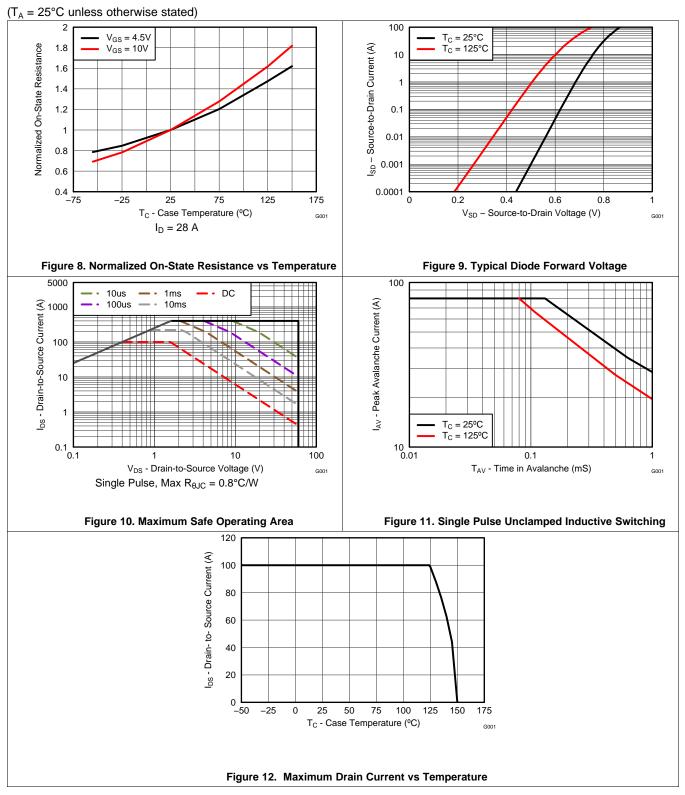




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Typical MOSFET Characteristics (continued)





6 Device and Documentation Support

6.1 Trademarks

NexFET is a trademark of Texas Instruments.

6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

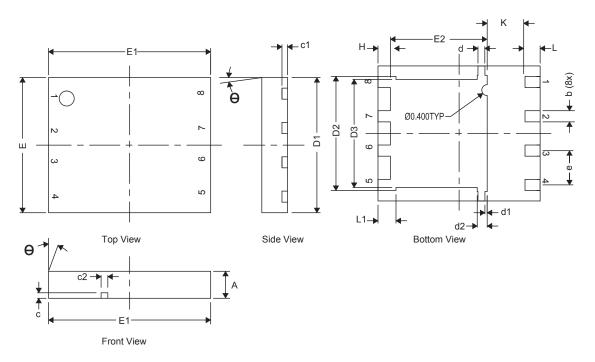


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7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Q5B Package Dimensions

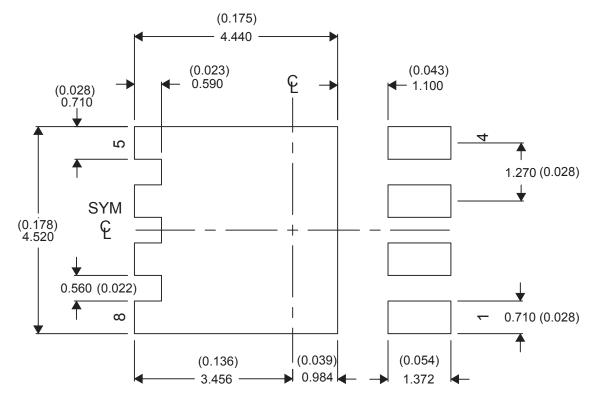


DIM	MILLIMETERS								
DIM	MIN	NOM	MAX						
A	0.80	1.00	1.05						
b	0.36	0.41	0.46						
С	0.15	0.20	0.25						
c1	0.15	0.20	0.25						
c2	0.20	0.25	0.30						
D1	4.90	5.00	5.10						
D2	4.12	4.22	4.32						
D3	3.90	4.00	4.10						
d	0.20	0.25	0.30						
d1		0.085 TYP							
d2	0.319	0.369	0.419						
E	4.90	5.00	5.10						
E1	5.90	6.00	6.10						
E2	3.48	3.58	3.68						
е		1.27 TYP							
Н	0.36	0.46	0.56						
L	0.46 0.56		0.66						
L1	0.57	0.67	0.77						
θ	0°	—	—						
К	1.40 TYP								

8

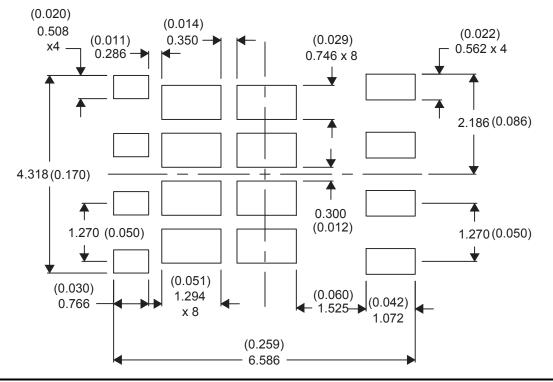


7.2 Recommended PCB Pattern



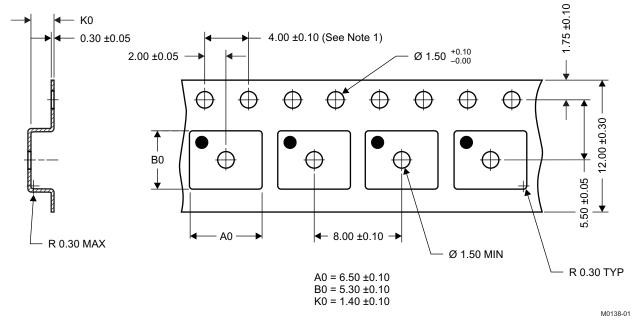
For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

7.3 Recommended Stencil Pattern



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7.4 Q5B Tape and Reel Information



Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified).
- 5. A0 and B0 measured on a plane 0.3 mm above the bottom of the pocket



30-Sep-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD18540Q5B	ACTIVE	VSON-CLIP	DNK	8	2500	Pb-Free (RoHS Exempt)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 150	CSD18540	Samples
CSD18540Q5BT	ACTIVE	VSON-CLIP	DNK	8	250	Pb-Free (RoHS Exempt)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 150	CSD18540	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

30-Sep-2014

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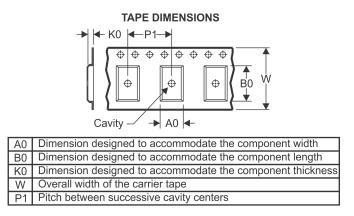
PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD18540Q5B	VSON- CLIP	DNK	8	2500	330.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1

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PACKAGE MATERIALS INFORMATION

18-Aug-2014



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD18540Q5B	VSON-CLIP	DNK	8	2500	367.0	367.0	35.0

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